

Bipolar Hall Effect Position Sensor

◆ General Description

GH2101 is a Bipolar Hall-effect IC, designed in BiCMOS technology, consists of devices that feature fast power-on time and low-noise operation. The GH2101 offer superior stability and stress-resistance and include voltage regulator, Hall-voltage generator, small-signal amplifier, Schmitt trigger, and NMOS output transistor. While the magnetic flux density is larger than operate point (BOP), the output will be turned off (High) and the output is latched "off" state until the magnetic flux density is lower than release point (BRP), then turn on (Low). The GH2101 can operate in the Voltage range of 3~24V and the temperature range of -40~+150°C.

The small geometries of the BiCMOS process allow these devices to be provided in ultra small packages. The GH2101 is available in SOT23-3L.

◆ Features

- Operating voltage range: 3~24V
- Operating temperature range: -40~+150°C
- Fast power-on time
- Low NOISE
- Reverse-battery protection
- Robust EMC performance
- Regulator stability without a bypass capacitor

◆ Applications

- Motion detector
- Automotive smart cockpit
- Industrial motor commutation
- Proximity detector
- Medical devices utilizing motors

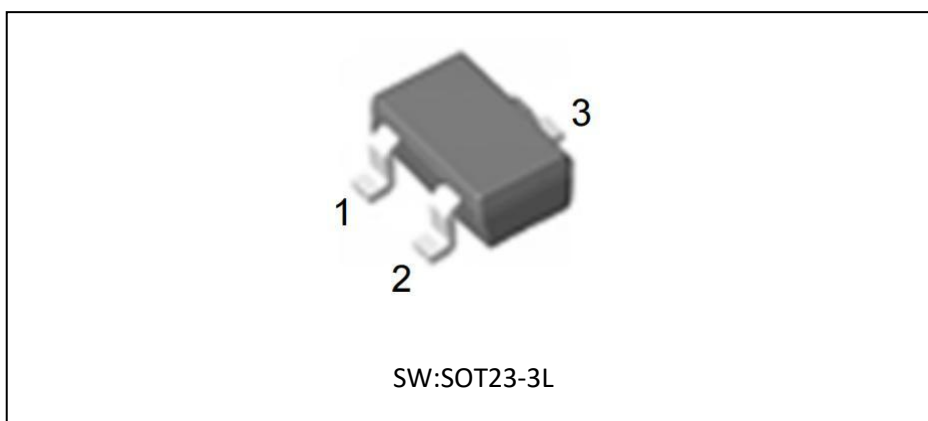


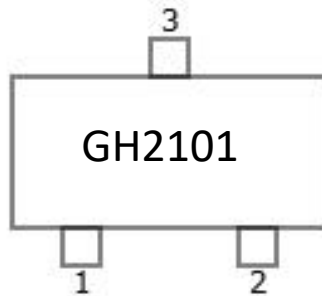
Figure 1 .Package Type of GH2101

◆ Ordering information

| Product | Package | Marking ID | Packing Type | Quantity |
|-----------|----------|------------|--------------|----------|
| GH2101LSW | SOT23-3L | GH2101 | Bulk | 3000pic |

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◆ **Pin Configuration**



| Pin | Pin Name | Function |
|-----|----------|--------------|
| 1 | VCC | Power supply |
| 2 | VOUT | Output |
| 3 | GND | Ground |

◆ **Functional Block Diagram**

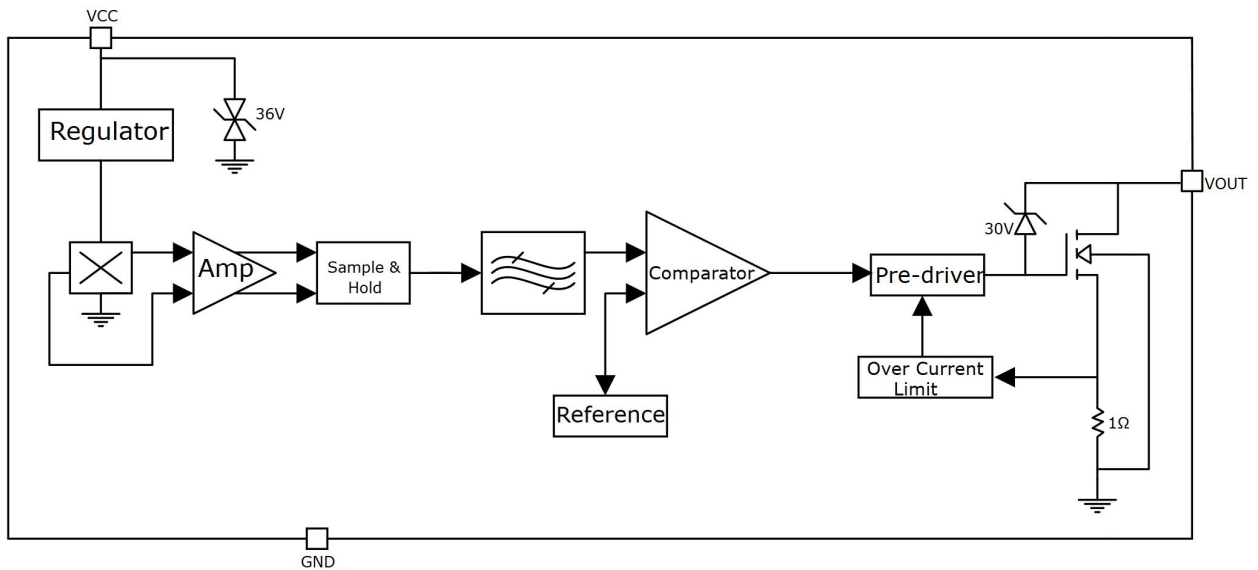


Figure 2 .Block Diagram of GH2101

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◆ Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$ (Note)

| Parameter | Symbol | Value | Unit |
|------------------------|---------------|----------|------------------|
| Supply Voltage | V_{CC} | 36 | V |
| Reverse Supply Voltage | V_{RCC} | -36 | V |
| Output Off Voltage | V_{OUT} | 30 | V |
| Reverse Output Voltage | V_{RCC} | -0.5 | V |
| Output Current | $I_{OUTSINK}$ | 40 | mA |
| Operation Temperature | T_A | -40~+150 | $^\circ\text{C}$ |
| Junction Temperature | $T_{j(max)}$ | +165 | $^\circ\text{C}$ |
| Storage Temperature | T_{ST} | -65~+170 | $^\circ\text{C}$ |

Note:

- 1) If any one of the maximum ratings is exceeded, the device may be damaged.
- 2) The maximum power supply voltage that can work normally must be adjusted according to the constraints of junction temperature and power consumption.

◆ Electrical Characteristics

$V_{DD} = 12\text{V}$, $T_A = 25^\circ\text{C}$, unless otherwise specified.

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|----------------------------|----------------|--|-----|-----|-----|---------------|
| Supply Voltage | V_{CC} | Operating | 3 | -- | 24 | V |
| Output Leakage Current | I_{OUTOFF} | $V_{OUT} = 24\text{V}$, $B < BRP$ | -- | -- | 10 | μA |
| Output On Voltage | $V_{OUT(SAT)}$ | $I_{OUT} = 20\text{mA}$, $B > BOP$ | -- | 160 | 400 | mV |
| Supply Current | I_{CCON} | $B > BOP$ | -- | 3.7 | 7.5 | mA |
| | I_{CCOFF} | $B < BRP$ | -- | 3.5 | 7.5 | mA |
| Output Rise Time | t_r | $V_{CC} = 12\text{V}$, $R_L = 820\Omega$, $C_{OUT} = 12\text{pF}$ | -- | -- | 1.7 | μs |
| Output Fall Time | t_f | $V_{CC} = 12\text{V}$, $R_L = 820\Omega$, $C_{OUT} = 12\text{pF}$ | -- | -- | 400 | μs |
| Reverse Battery Current | I_{RCC} | $V_{RCC} = -36\text{V}$ | -- | -- | -10 | mA |
| Supply Zener Clamp Voltage | V_Z | $I_{CC} = 5\text{mA}$, $T_A = 25^\circ\text{C}$ | 36 | -- | -- | V |
| Supply Zener Current | I_Z | $V_Z = 36\text{V}$, $T_A = 25^\circ\text{C}$ | -- | -- | 5 | mA |

◆ Magnetic Characteristics

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|---------------|--------|--|-----|-----|-----|------|
| Operate Point | BOP | $V_{CC} = 12\text{V}$, $T_A = 25^\circ\text{C}$ | -- | 85 | -- | GS |
| Release Point | BRP | $V_{CC} = 12\text{V}$, $T_A = 25^\circ\text{C}$ | -- | -85 | -- | GS |
| Hysteresis | BHYS | $V_{CC} = 12\text{V}$, $T_A = 25^\circ\text{C}$ | -- | 170 | -- | GS |

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◆ **Functional Description**

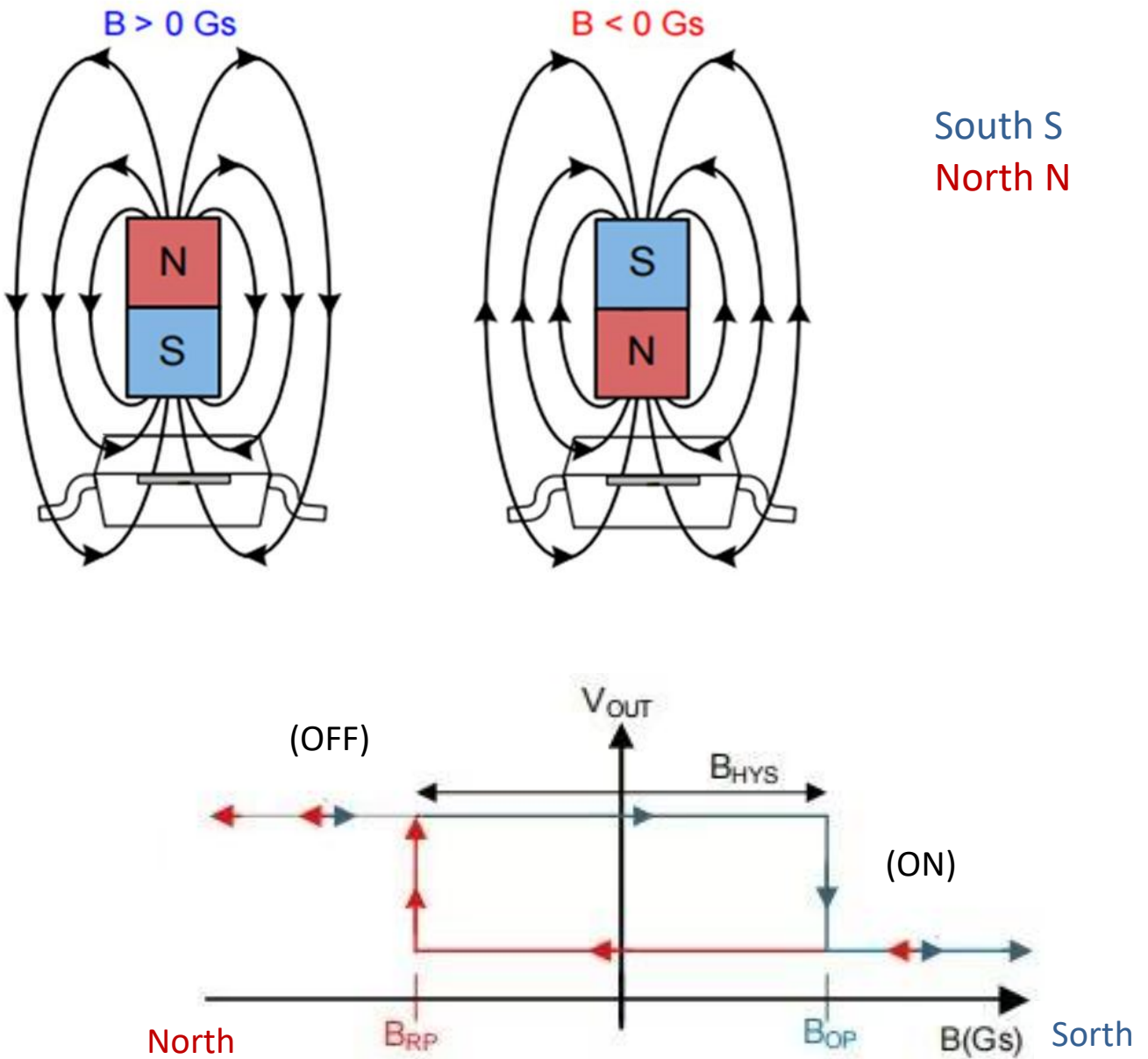
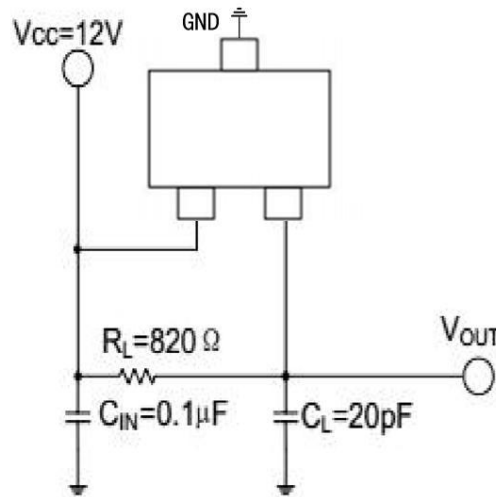


Figure 3 Output characteristics of GH2101

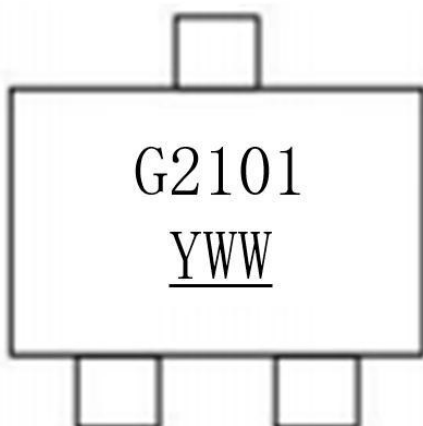
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◆ **Typical Application**



Note: C_{IN} is used to stabilize external power supply; R_L is the pull-up resistance necessary for open collector output, depending on the current capacity required by the back-end input; C_L is used to filter out the output noise. This capacitor will affect the rise time of the waveform.

◆ **Marking Information**

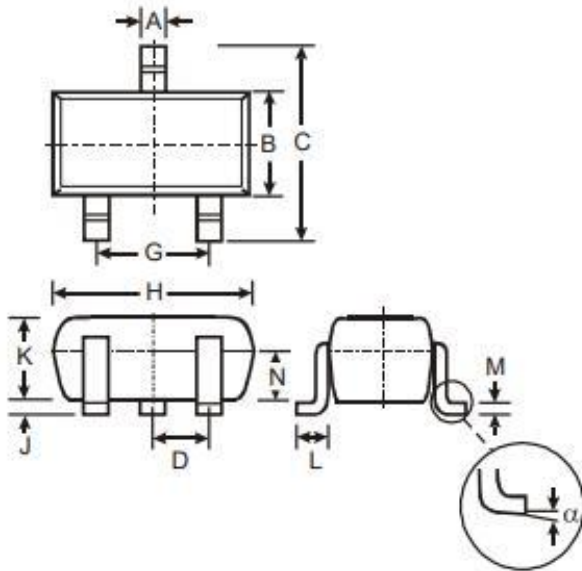


Y: Year: " 4 " = 2024

WW: Nth Week 01 ~ 52

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◆ **Package Information**




| Dim | Min | Max | Typ |
|-----------------------------|-------|------|------|
| A | 0.35 | 0.50 | 0.38 |
| B | 1.50 | 1.70 | 1.60 |
| C | 2.70 | 3.00 | 2.80 |
| D | - | - | 0.95 |
| G | - | - | 1.90 |
| H | 2.90 | 3.10 | 3.00 |
| J | 0.013 | 0.10 | 0.05 |
| K | 1.00 | 1.30 | 1.10 |
| L | 0.35 | 0.55 | 0.40 |
| M | 0.10 | 0.20 | 0.15 |
| N | 0.70 | 0.80 | 0.75 |
| α | 0° | 8° | - |
| All Dimensions in mm | | | |

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